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Hands On Electronics Presented by:

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Department: Science and Technology REPUBLIC OF SOUTH AFRICA



Hands On Electronics



Electronics lab @ JINR University Centre







Hands On Electronics

Overview :

- □ Introduction.
- Aim and objectives
- □ Literature Review
- □ Materials and methods(Practical venue, Materials used).
- Results and discussion
- Conclusion
- References
- Acknowledgements
- Questions





introduction







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Aim and objectives

Aim: To experimentally study the main electronic components and circuits.

Objectives:

- To learn about measuring devices and soldering theory.
- □To study electronic-elements.
- Calculation of filter parameters.
- □To study semi-conductor properties.
- Calculation of transistor amplifier cascades.
- Amplifier testing with cosmic detectors.



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Literature review







- $\Box \tau = RC$ Is called the time constant of the capacitor, i.e. the time it takes the capacitor to be 63% of full charge.
- The capacitor has got an impedance which relates to the cutoff frequency and capacitance as: $X_c = \frac{1}{2\pi f_c C}$





2. Rectifier circuit

Half Wave rectifier







Rectifier circuit cont.

Full wave rectifier







Rectifier circuit cont.

rectifier filter







3. Transistor Circuits



Fig3.3





Transistor Circuits cont.

Table 3.1 : Properties of CEC, CCC and CBC

CEC	ССС	СВС
 High current gain. High voltage gain. Inverted output signal. 	 High input resistance. Low output resistance. High current gain Low voltage gain 	 High allowable voltage. Low output resistance . High Current gain. Low voltage gain.





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Materials and methods used



Soldering iron



Function generator



Oscilloscope and DC power supply



Circuit board and circuit components







Procedure















Common Emitter Circuit













Common Emitter Circuit cont..

- $\Box I_{c} = 3mA, Chosen.$ $\Box U_{in} = 200mV$ $\Box k = \frac{U_{out}}{U_{in}} = 10$
- The signal was inverted and amplified





Preamplifier on CCC and BCC



 $I_{R5} = I_{eVT1} \approx I_{R1} \dots \dots \dots 1$ $I_{R5} = \frac{U2 - 0.7V}{R5} \dots \dots \dots 2$ $R2 = \frac{U1 - U_{eVT2}}{I_{eVT2}} \dots \dots 3$ $U_{eVT2} = U1 - I_{c1}R1 - U_{beVT2}$





results and discussions Preamplifier on CCC and BCC cont..







Preamplifier on CCC and BCC cont.







CONCLUSION

The objectives of this project were achieved since we learnt with understanding, the electronic elements, could perform calculations on high and low pass filters, understood the properties of semi-conductor devices of electronics and could use calculations of transistor amplifiers to connect circuits which were tested on a cosmic ray detector.





references

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□Smith R. J., Dorf R. C. Circuits, devices and systems. – John Wiley & Sons, 2009.





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